

FEATURES

- * 0.3 inch (7.62 mm) DIGIT HEIGHT.
- * CONTINUOUS UNIFORM SEGMENTS.
- * LOW POWER REQUIREMENT.
- * EXCELLENT CHARACTERS APPEARANCE.
- * HIGH BRIGHTNESS & HIGH CONTRAST.
- * WIDE VIEWING ANGLE.
- * SOLID STATE RELIABILITY.
- * CATEGORIZED FOR LUMINOUS INTENSITY.

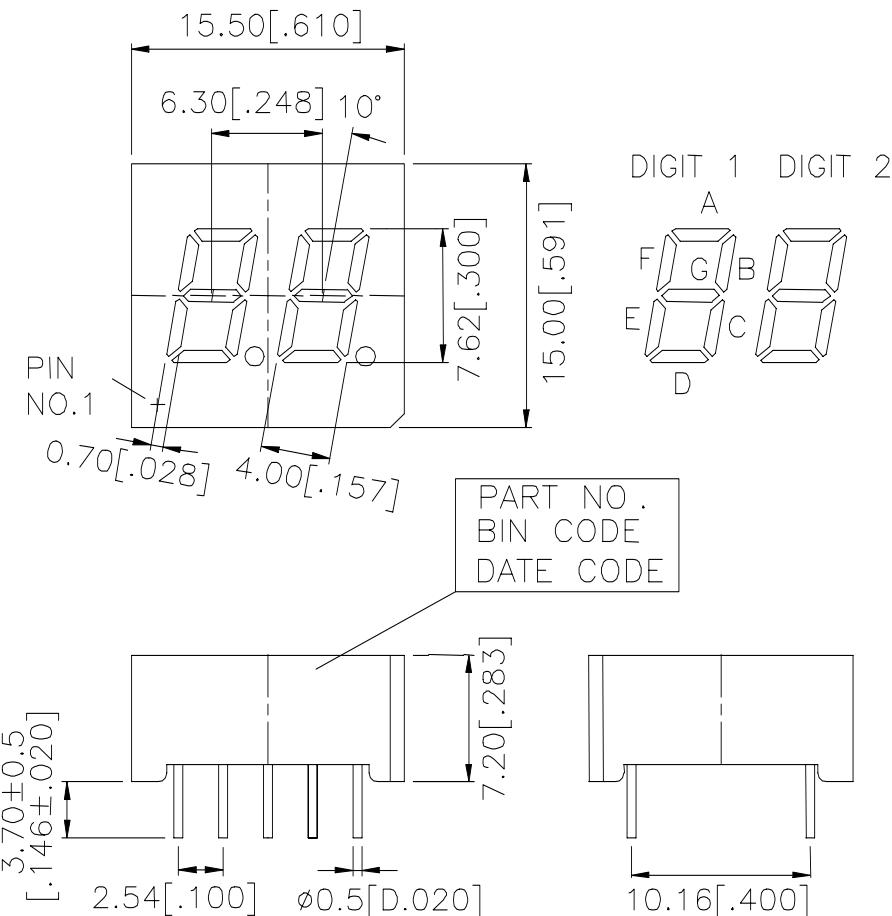
DESCRIPTION

The LTD-322JR is a 0.3 inch (7.62 mm) digit height display. This device utilizes AlInGaP Super Red LED chips, which are made from AlInGaP on a non-transparent GaAs substrate, and has a black face and white segments.

DEVICE

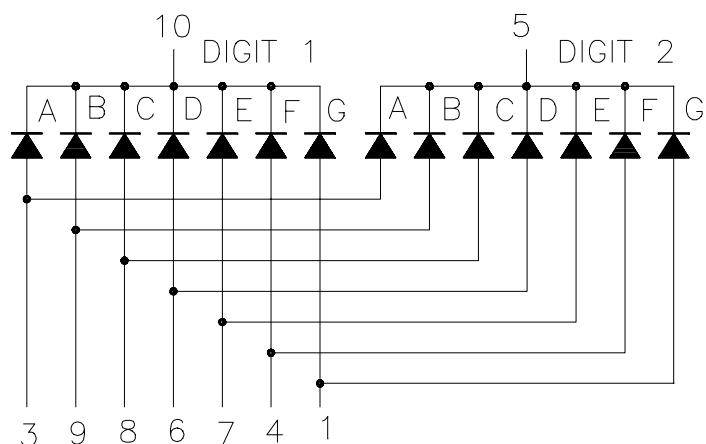
PART NO.	DESCRIPTION
AlInGaP Super Red	
LTD-322JR	Duplex Common Cathode

PACKAGE DIMENSIONS



NOTES: All dimensions are in millimeters. Tolerances are ± 0.25 mm (0.01") unless otherwise noted.

INTERNAL CIRCUIT DIAGRAM



PIN CONNECTION

No	CONNECTION
1	ANODE G
2	NO PIN
3	ANODE A
4	ANODE F
5	COMMON CATHODE (DIGIT 2)
6	ANODE D
7	ANODE E
8	ANODE C
9	ANODE B
10	COMMON CATHODE (DIGIT 1)

ABSOLUTE MAXIMUM RATING AT Ta=25°C

PARAMETER	MAXIMUM RATING	UNIT
Power Dissipation Per Segment	70	mW
Peak Forward Current Per Segment (1/10 Duty Cycle, 0.1ms Pulse Width)	90	mA
Continuous Forward Current Per Segment	25	mA
Derating Linear From 25 Per Segment	0.33	mA/
Reverse Voltage Per Segment	5	V
Operating Temperature Range	-35 to +85	
Storage Temperature Range	-35 to +85	
Solder Temperature: max 260 for max 3sec at 1.6mm below seating plane.		

ELECTRICAL / OPTICAL CHARACTERISTICS AT Ta=25°C

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I _v	200	600		μcd	I _F =1mA
Peak Emission Wavelength	λ _p		639		nm	I _F =20mA
Spectral Line Half-Width	Δλ		20		nm	I _F =20mA
Dominant Wavelength	λ _d		631		nm	I _F =20mA
Forward Voltage Per Segment	V _F		2.0	2.6	V	I _F =20mA
Reverse Current Per Segment	I _R			100	μA	V _R =5V
Luminous Intensity Matching Ratio	I _v -m			2:1		I _F =1mA

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

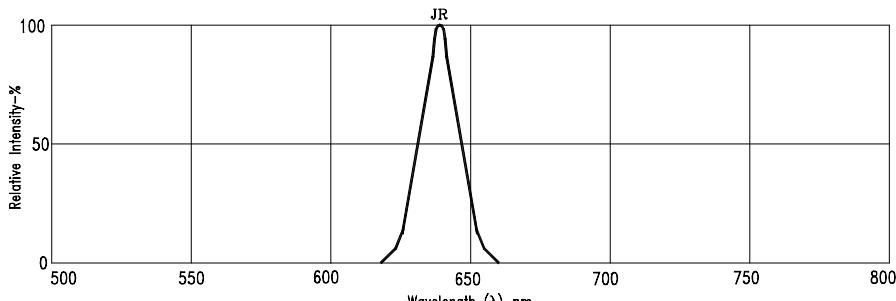
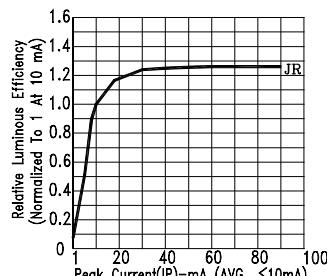
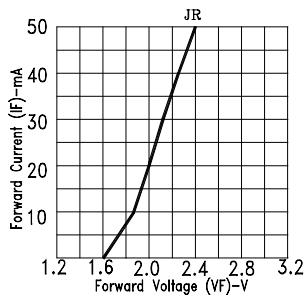
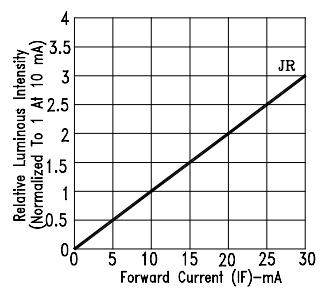
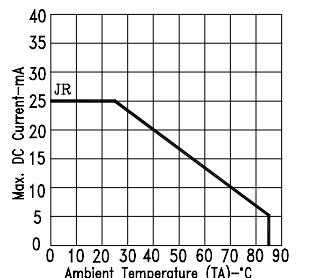
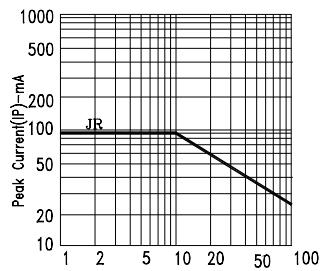


Fig.1. RELATIVE INTENSITY VS. WAVELENGTH

Fig.2. RELATIVE LUMINOUS EFFICIENCY
(LUMINOUS INTENSITY PER UNIT
CURRENT) VS. PEAK CURRENTFig.3. FORWARD CURRENT VS.
FORWARD VOLTAGEFig.4. RELATIVE LUMINOUS INTENSITY
VS. FORWARD CURRENTFig.5. MAX. ALLOWABLE DC CURRENT
VS. AMBIENT TEMPERATURE.Fig.6. MAX. PEAK CURRENT VS.
DUTY CYCLE %
(REFRESH RATE 1KHz)

NOTE : JR=AlInGaP SUPER RED